

HN1A01FE-GR,LF

HN1A01FE-GR,LF Information

F	Nummersener, com	HN1A01FE-GR,LF Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays TRANS 2PNP 50V 0.15A ES6 SOT-563, SOT-666 For the pricing/inventory/lead time, please contact	
	For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



HN1A01FE-GR,LF Specifications

Manufacturer Part Number	HN1A01FE-GR,LF
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays
Package	SOT-563, SOT-666
Series	-
Transistor Type	2 PNP (Dual)
Current - Collector (Ic) (Max)	150mA
Voltage - Collector Emitter Breakdown (Max)	50V
Vce Saturation (Max) @ Ib, Ic	300mV @ 10mA, 100mA
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	200 @ 2mA, 6V
Power - Max	100mW
Frequency - Transition	80MHz
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-563, SOT-666
Supplier Device Package	ES6
	Report errors?
	Report citors:

HN1A01FE-GR,LF Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

HN1A01FE-GR,LF Payment Methods



HN1A01FE-GR,LF Shipping Methods



If you have any question about HN1A01FE-GR,LF, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com